

## **GSM-20H10**

#### **Source Measure Unit**

#### **FEATURES**

- Maximum Output ±210V/±1.05A/22W
- Built-in 4 Sequence Output Modes (Stair, Log, SRC-MEM, Custom), up to 2500 Points
- OVP /OTP Protection Function
- 0.012% Basic Measure Accuracy with 6½-digit Resolution
- Variable Sampling Speed
- SDM (Source Delay Measure) Cycle
- 2-, 4-, and 6-wire Remote V-source and Measure Sensing
- Variable Display Digits
- Built-in Limit Function
- Built-in 5 Calculation Functions
- 4.3" TFT LCD, Digital Number Keyboard
- Built-in RTC Clock
- Interface: RS-232, USBTMC, LAN, GPIB (Optional)

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## **Streamline Your Characteristic Analysis**

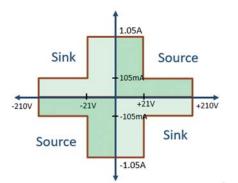
GW Instek GSM-20H10 is a Source Measure Unit that provides highly stable DC power and instrument-grade 6½-digit multimeter measurements. While operating, it can be used as a voltage source, current source, voltmeter, ammeter, and ohmmeter, which is uniquely ideal for the evaluation of component characteristics and the test applications of production, including nanomaterials and components, semiconductor architecture, organic materials, high-efficiency illumination, passive components and material characteristics analysis, etc.

GSM-20H10 provides four-quadrant operation of  $\pm 210V/\pm 1.05A/22W$ . The first and third quadrants operate as power supplies to supply power to the load. The second and fourth quadrants function as loads to consume power internally. Voltage value, current value and resistance value can be measured while operating the power supply or load function with an accuracy of 0.012% and a resolution of  $1\mu V/10pA/10\mu \Omega$ .

With respect to sampling rate, GSM-20H10 supports a sampling rate of up to 50k points/second, which can accurately analyze the characteristics of the DUT. With the large 4.3-inch screen, all measurement settings, parameters and results can be completely displayed on the screen. The SDM (Source Delay Measure) function is provided to delay sampling when the signal changes so as to prevent the unstable signal from being captured and cause misjudgment. There are four built-in sequence output modes (Stair, Log, SRC-MEM, Custom), which can support up to 2500 points of sequence variation output.

Pertaining to protection, GSM-20H10 provides OVP/OTP modes. The design of OVP allows users to self-define the range of OVP. OTP can effectively prevent errors caused by temperature drift during the test process. For interfaces, this product supports standard SCPI commands and provides RS-232, USBTMC, LAN, GPIB (optional) interfaces to meet users' different interface needs.

#### A. MAXIMUM OUTPUT: ±210V/±1.05A/22W

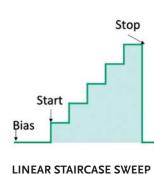


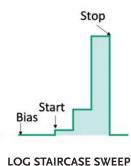
The power source output of the GSM-20H10 has two ranges.

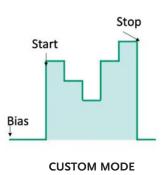
The voltage range is  $\pm 21$  volts, and the current is  $\pm 1.05A$ . The voltage range is  $\pm 210$  volts, and the current range is  $\pm 105$ mA. The power capacity is 22W.

Provide a full range of four-quadrant measurement without duty cycle limit.

#### B. BUILT-IN 4 SEQUENCE OUTPUT MODES, UP TO 2500 POINTS







GSM-20H10 Source Measure Unit provides four sequence output modes: linear staircase, log staircase, SRC-MEM (source memory) and Custom(self-defined). With these output modes, users can quickly generate output as needed. The total number of sequence points is 2,500.

#### C. OVP /OTP PROTECTION FUNCTION

# Measure 60Hz FAR ICIA FCV ARIA FRID DVM EBR 41\*C OVP state: 0000 Source 50Hz FAR ICIA FOVD FAR 32\*C Auto delay: 5mate OVP state: 50Hz FAR ICIA FOVD FAR 32\*C Auto delay: 5mate OVP state: 50Hz FAR ICIA FOVD FAR 32\*C Vorc trig control: 0100000005 Value: 2000 FAR ICIA FOVD FAR 32\*C Vorc trig control: 0100000 Auto delay: fmate Delay: 0000 FAR ICIA FAR ICIA

In terms of protection, GSM-20H10 provides OVP/OTP protection modes; in the design of OVP, users can define the range of OVP, and the protection of OTP can effectively prevent errors caused by temperature drift during the test process.



GSM-20H10 provides a measurement accuracy of up to 0.012%, and provides a meter display function of up to  $6\frac{1}{2}$  digits, allowing users to have more accurate results when measuring small signals..

#### VARIABLE SAMPLING SPEED

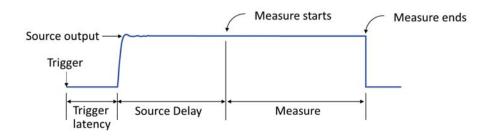


SAMPLING MODE	FAST	MEDIUM	NORMAL	HIGH	OTHER
Speed, NPLC	0.01	0.1	1	10	User defined
Digit	3½	4½	5½	6½	Selectable

The sampling rate of GSM-20H10 is variable. Therefore, users can choose the sampling rate from 0.01 PLC to 10 PLC according to their needs.

Where NPLC represents the number of power line cycles, for example, AC power frequency is 50Hz, 1 PLC means 20ms, 2 PLC means 40ms, and so on.

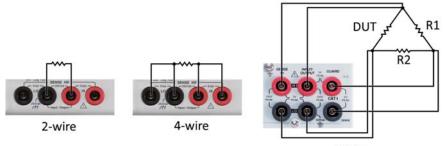
#### F. SDM (SOURCE DELAY MEASURE) CYCLE



The initial state of the source output may be unstable. If the meter starts measuring after the source is output, users can set the source delay to start the meter measurement after passing the unstable period so as to obtain stable measurement results. GSM-20H10 Source Measure Unit delay range is 0 to 9999.999 seconds.

#### D. 0.012% BASIC MEASURE ACCURACY WITH 6<sup>1</sup>/<sub>2</sub>DIGIT RESOLUTION

#### G. 2-, 4-, AND 6-WIRE REMOTE V-SOURCE AND MEASURE SENSING





Other than 2-wire, GSM-20H10 also provides 4-wire and 6-wire resistance measurements.

4-wire measurement eliminates the effect of lead resistance, realizing accurate measurement of small resistances below 1000hm at high currents. 6-wire combining 4-wire connection and the protection of ohm characteristics eliminate the effects of internal parallel resistance, realizing the resistance measurement of a tiny wire.

#### H. VARIABLE DISPLAY DIGITS



The display bits of GSM-20H10 are variable. Therefore, users can choose the number of display bits among 3.5, 4.5, 5.5, and 6.5 bits according to their needs.

#### BUILT-IN LIMIT FUNCTION

Digout size: 16bit Mode: Grading Sorting fail: 0	Pass pattern: Source mem Location:	anula	mit _	60Hz	R NEM (	V ARM I	RG DSP I	41°C
Grading: Immediate Auto clear: Disable				Low -1.000000			ligh 1.000000_	Hi_fail 15
Clear pattern: 15		L03:					1.000000_	
Clear delay: 0.00010		L05:						
		1.06						
HW-Control: Disaste	End of test m							
Fail mode: In		L08:						
CMPL pattern: 15								
Digout HW-Limits SW-Lim	its Pass							
Digout mines on-bit	1 1 1 1 1 1	L11:						
		L12:	Disable					
		Dis	zout	HW-Limits	SW-Limits	Pass	EOT-Mode	Cancel

GSM-20H10 has three built-in Pass/Fail limit line tests with a total of 11 sets.

#### J. BUILT-IN 5 CALCULATION FUNCTIONS

•	Power :	= V*I
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- CompOhms =  $\frac{(V2-V1)}{(I2-I1)}$
- Vceoff(%) =  $\left[\frac{\Delta R}{\{R2 * \Delta V\}}\right] * 100\%$
- VarAlpha,  $\alpha = \frac{log(l2+l1)}{log(v2+V1)}$
- Dev =  $\left[\frac{(X-Y)}{Y}\right] * 100\%$



GSM-20H10 provides five built-in calculation functions: Power, Offset Compensation Ohms, Voltage Coefficient, Varistor Alpha, and Percent Deviation.

#### CE RS-232 USB USB LAN Digit GPIB





- 1. LCD Display
- 2. USB Host
- 3. Number Pad/ Secondary Function Key
- 4. Power On/Off Button
- 5. Direction Keys And Enter Key
- 6. Function Key
- 7. Front Panel Input/Output Terminals
- 8. Auxiliary Function Key
- 9. AC Power Switch
- 10. GPIB Port (Option)
- 11. Heat Sink Fan
- 12. LAN
- 13. USB Device
- 14. Real Panel Inputs/Outputs
- 15. RS-232
- 16. Digital I/O
- 17. AC Power Socket and Fuse

	Voltage		±210V												
	Current		±1.05A												
MAXIMUM RANGE	Power		22W												
RANGE	Voltage Resoluti	on	1μV												
	Current Resoluti	on	10pA												
		Output Voltage	±21V / ±1.05A, ±2	10V / ±105 mA											
		Current Limit	Min. 0.1% of rang												
		Programming Resolution &	Range ±200.000mV			±2.00000V		±20.0000V	±í	200.000V					
		Accuracy *1	Resolution	n 1µV		10µV		100µV	1mV						
		,	Accuracy	±(0.02%+60	00μV)	±(0.02%+600µV)		±(0.02%+2.4mV)	±(0.0	)2%+24mV)					
	DC Voltage	Load Regulation	0.01% of range +	01% of range + 100µV											
	DC Voltage	Line Regulation	0.01% of range	.01% of range											
		Overshoot	<0.1% typical (full scale step,resistive load, 10mA range)												
		Recovery Time (1000% Load Change)	<250µs (within 0.1% plus load regulation errors, 1A and 100mA compliance )												
		Ripple and Noise	4mVrms(20Hz~1MHz) / 10mVpp(20Hz~1MHz)												
		Temperature Coefficient	±(0.15 × accuracy specification)/*C (0"-18°C & 28"-50°C)												
		Output Current	±1.05A / ±21V, ±105 mA / ±210V												
		Voltage Limit	Min. 0.1% of range												
OURCE		Programmed Source Resolution & Accuracy *1	Range	±1.00000µA	±10.0000µA	±100.000µA	±1.00000mA	±10.00000mA	±100.000mA	±1.00000A					
			Resolution	10pA	100pA	1nA	10nA	100nA	1μA	10µA					
	DC Current		Accuracy	±(0.035%+600pA)	±(0.033%+2nA)	±(0.031%+20nA)	±(0.034%+200nA)	±(0.045%+2µA)	±(0.066%+20µA)	±(0.27%+900µ/					
		Load Regulation	0.01% of range + 100pA												
		Line Regulation	0.01% of range												
		Overshoot		<0.1% typical (1mA step, RL = 10kΩ, 20V range)											
		Temperature Coefficient	±(0.15 x accuracy specification)/°C (0°-18°C & 28°-50°C)												
		Output Settling Time *2	100µs typical time												
		Output Rise Time (±30%)		, 100mA compliance ; 150	)µs, 20V range, 100mA co	mpliance									
		DC Floating Voltage		ited up to ±250VDC											
	General	Remote Sense	Up to 1V drop per												
	Jeneral	Compliance Accuracy		and ±0.02% of reading to											
		Range Change Overshoot *3		anges between 200mV, 2V	and 20V ranges, 100mV	typical									
		Minimum Compliance Value	0.1% of range												
		Command Processing Time *4	Autorange On:10r	ns. Autorange Off: 7ms											

CDECIEN	CATIONS											_				
SPECIFIC	CATIONS															
		Input Resistance	>10 GΩ													
		Measurement Resolution &	Range ±200.000mV			±2.00000V				±20.0000V			±200.000V			
	Voltage	Accuracy	Resolution 1µV					10µV			100µV			1mV		
			Accuracy	Accuracy ±(0.012%+300µV) ±(0.015%+1.5mV) ±(0.015%+1.5mV) ±(0.015%+ ±(0.15 × accuracy specification)/°C (0°-18°C & 28°-50°C)										.015%+10mV)		
		Temperature Coefficient		specification)/°C (0°~	-18°C & :	28°~50°C)										
		Voltage Burden (4-wire mode)	< 1mV													
		Programmed Source Resolution &	Range	±1.00000µA		±10.0000µA	±l	00.000μΑ		000mA	±10.00000n			±1.00000A		
	Current	Accuracy *1	Resolution	10pA		100pA		1nA 10			100nA			10µA		
			Accuracy	±(0.029%+300pA)		±(0.027%+700pA)	±(0.0	025%+6nA)	±(0.0275	%+60nA)	±(0.035%+60	UnA)	±(0.055%+6µA)	±(0.22%+570μA		
		Temperature Coefficient	$\pm (0.1 \times \text{accuracy s})$	pecification) / °C (0°- <2.00000Ω	-18.0 &.	28'~50'C) 2.00000	0	20.0	000.0	200	.000Ω	2.00000kΩ 20.0000kΩ				
			Resolution	<2.000001		2.00000		20.0000Ω 100μΩ			mΩ	2.0000kΩ 10mΩ		20.0000kΩ 100mΩ		
MEASUREMENT			Test current		10µ52			10mA		1mA		100µA				
MENJOREMENT								+(0.1%+0.003(0) Normal		±(0.08%+0.03Ω), Normal		±(0.07%+0.3Ω), Normal		±(0.06%+3Ω), Norm		
			Accuracy	Source IACC+Meas	.VACC	Source IACC+M	eas.VACC				1 Ω), Enhanced		.1Ω), Enhanced	±(0.04%+1Ω), Enhance		
		Range	200.000kΩ 2.0000		2.00000	40	20.0000MΩ			000MΩ	>200.000M Ω		=(0101)01111/1 =1110110			
			Resolution	1Ω		10Ω			00Ω		1kΩ					
	Resistance		Test current	10µA		5µA		0.	5µA	1	00nA					
			Accuracy	±(0.07%+30Ω), No	ormal	±(0.11%+300Ω)	), Normal		kΩ), Normal	±(0.66%+1	0kΩ), Normal	Source 14C	C+Meas.VACC			
			Accuracy	±(0.05%+10Ω), Enh		±(0.05%+100Ω),	Enhanced	±(0.05%+500	DΩ), Enhanced	±(0.35%+5	kΩ), Enhanced	Source IAC	C+IVIEas.VACC			
		Temperature Coefficient		specification)/°C (0°~												
		Source I mode, Manual OHMS		= I source accuracy + \												
		Source V mode, Manual OHMS		= V source accuracy +												
		6-wire OHMS Mode		tive ohms guard and §	guard sei	nse. Max. Guard O	utput Curren	t: 50mA (exce	ept 1A range). A	curacy is load	l dependent					
		Guard Output Impedance	<0.1Ω in ohms m	ode												
	Maximum Range C		75/second													
	Maximum Measure	Auto kange lime	40ms (fixed source				C .		10	C	A	l tratila i a		Managements		
		Speed	NPLC / Trig	TO MEMORY	Measure EMORY TO GPIB		TO MEMOR	Source-Measure *9 DRY TO GPIB		TO MEM	Aeasure Pass/Fai	O GPIB	TO MEMOR	sure Memory *9 TO GPIB		
	Comment Deadland	Fast	Origin 0.01 / internal	2081 (2030)		98 (1210)	1551 (1515		000 (900)	902 (90		0 GPIB 09 (840)	165 (162)	164 (162)		
	Sequence Reading Rates *7	488.2	0.01 / Internal	1239 (1200)		79 (1210)	1018 (990)		900 (900) 916 (835)	902 (90		56 (780)	163 (162)	164 (162)		
	(rdg./second) for	400.2 Medium	0.01 / external	510 (433)		09 (433)	470 (405)		170 (410)	389 (34		88 (343)	133 (126)	132 (126)		
	60Hz (50Hz)	488.2	0.1 / external	438 (380)		38 (380)	409 (360)		109 (365)	374 (33		74 (333)	131 (125)	131 (125)		
		Normal	1 / internal	59 (49)		59 (49)	58 (48)		58 (48)	56 (47		56 (47)	44 (38)	44 (38)		
SYSTEM		488.2	1 / external	57 (48)		57 (48)	57 (48)		57 (47)			56 (47)	44 (38)	44 (38)		
SPEED *5	cial partici	Grand	NPLC/ Trig Measure Source-Measure *9									5	Source-Measure Pa	ss/Fail test *8, *9		
	Single Reading Operation Rates	Speed	Origin TO GPIB						TO	SPIB			TO GR	ΊB		
	(rdg./second) for	Fast(488.2)	0.01 / internal		(256)		79 (83)			79 (83)						
	60Hz (50Hz)	Medium(488.2)	0.1 / internal		(166)	72 (70)					69 (7					
	••••=(••••=)	Normal(488.2)	1 / internal	(42)	34 (31)						35 (3)					
	Component	Speed	NPLC / Trig Measure							ss/Fail test		S	ource-Measure Pas			
	Interface Handler	•	Origin         TO GPIB           0.01 / internal         1.04 ms (1.08 ms)							SPIB			TO GF			
	Time for 60Hz	Fast	0.01 / internal			0.5 ms			4.82 ms (5.3 ms) 6.27 ms (7.1 ms)							
	(50Hz) *8, *10	Medium Normal	0.1 / internal 1 / internal		2.55 ms	(2.9 ms) (20.9 ms)		0.5 ms (0.5 ms) 0.5 ms (0.5 ms)								
	Load Impedance	Normai	Stable into 20,000			0.5 ms (0.5 ms)					21.31 ms (25.0 ms)					
	Differential Mode V	oltage	250VPk	Pi (IPical												
	Common Mode Vo		250VDC													
	Common Mode Iso		>10GQ. <1000pF													
	Over Range			urce and measure												
	Max. Voltage Drop		5V													
	Max. Sense lead Re	sistance	1MΩ													
	Sense Input Impeda		>100GΩ													
	Guard Offset Voltag		<150µV, typical													
	Source Output Mod			emory List (mixed fund	ction), St	tair (linear and log	)									
SYSTEM			100 points max													
	Source Memory Lis		Too points max 5,000 readings @ 5 digits (two 2,500 point buffers). Includes selected measured value(s) and time stamp. Lithium battery backup(3 yr + battery life)													
	Memory Buffer	•			IEEE-488.2 (SCPI), RS-232 ; 5 user-definable power-up states plus factory default and *RST.											
	Memory Buffer Programmability		IEEE-488.2 (SCPI)	, RS-232 ; 5 user-defin	able pow				and ATTLED 1	Delug 1	- /11V@500 .	de das				
	Memory Buffer Programmability Digital I/O Connect		IEEE-488.2 (SCPI) Active low input.	, RS-232 ; 5 user-defin Start of test, end of tes	able pow				nput, 4 TTL/Rela	y Drive outpu	ts (33V@500mA,	, diode)				
	Memory Buffer Programmability Digital I/O Connect Remote Interface		IEEE-488.2 (SCPI) Active low input. USB/GPIB/LAN/I	, RS-232 ; 5 user-defin Start of test, end of tes RS-232	able pow it, 3 cate;	gory bits. ; +5V@ 3	300mA supply	y.; 1 trigger ir		y Drive outpu	ts (33V@500mA,	, diode)				
	Memory Buffer Programmability Digital I/O Connect Remote Interface Insulation	or	IEEE-488.2 (SCPI) Active low input. USB/GPIB/LAN/I Chassis and term	, RS-232 ; 5 user-defin Start of test, end of tes RS-232 nal : 20MΩ or above	able pow it, 3 cate; (DC 500\	gory bits. ; +5V@ 3 /) ; Chassis and AG	300mA supply	y. ; 1 trigger in Ω or above (D	OC 500V)			, diode)				
SYSTEM GENERAL	Memory Buffer Programmability Digital I/O Connect Remote Interface Insulation Operation Environm	or nent	IEEE-488.2 (SCPI) Active low input. USB/GPIB/LAN/I Chassis and term Indoor use, Altitu	, RS-232 ; 5 user-defin Start of test, end of tes RS-232 nal : 20MΩ or above de: ≤ 2000m Ambient	able pow it, 3 catej (DC 500\ tempera	gory bits. ; +5V@ 3 /) ; Chassis and AG	300mA supply	y. ; 1 trigger in Ω or above (D	OC 500V)			, diode)				
	Memory Buffer Programmability Digital I/O Connect Remote Interface Insulation Operation Environment Storage Environment	or nent	IEEE-488.2 (SCPI) Active low input. USB/GPIB/LAN/I Chassis and term Indoor use, Altitu Temperature: -20°	, RS-232 ; 5 user-defin Start of test, end of tes KS-232 inal : 20MΩ or above de: ≤ 2000m Ambient C ~ 70°C; Humidity: <	able pow it, 3 catej (DC 500\ tempera	gory bits. ; +5V@ 3 /) ; Chassis and AG	300mA supply	y. ; 1 trigger in Ω or above (D	OC 500V)			, diode)				
	Memory Buffer Programmability Digital I/O Connect Remote Interface Insulation Operation Environm	or nent nt	IEEE-488.2 (SCPI) Active low input. USB/GPIB/LAN/I Chassis and term Indoor use, Altitu	, RS-232 ; 5 user-defin Start of test, end of tes KS-232 inal : 20MΩ or above de: ≤ 2000m Ambient C ~ 70°C; Humidity: <	able pow it, 3 catej (DC 500\ tempera	gory bits. ; +5V@ 3 /) ; Chassis and AG	300mA supply	y. ; 1 trigger in Ω or above (D	OC 500V)			, diode)				

NOTE: 1. Speed = Normal (1 NPLC). For 0.1 PLC, add 0.005% of range to offset specifications, except 200mV, 1A ranges, add 0.05%. For 0.01 PLC, add 0.05% of range to offset specifications, except 200mV, 1A ranges, add 0.5%.

2. Required to reach 0.1% of final value after Command is processed. Resistive load.  $10\mu A$  to 100mA range.

3. Overshoot into a fully resistive 100 k  $\Omega$  load, 10Hz to 1MHz BW, adjacent ranges: 100mV typical, except 20V/200V.

Maximum time required for the output to begin to change following the receipt of : SOURce : VOLTage|CURRent <nrf> Command.
 Reading rates applicable for voltage or current measurements, autorange off, filter off, display off, trigger delay = 0, and binary reading forma.

6. Purely resistive lead. 1µA and 10µA ranges <65ms.

7. 1000 point sweep was characterized with the source on a fixed rang.

8. Pass/Fail test performed using one high limit and one low math limit.

Includes time to re-program source to a new level before making measurement.
 Time from falling edge of START OF TEST signal to falling edge of END OF TEST signal.
 Command processing time of : SOURce : VOLTage|CURRent : TRIGgered <nrf> Command not included.

#### ORDERING INFORMATION

GSM-20H10 with GPIB GSM-20H10

Source Measure Unit Source Measure Unit

OPTIONAL ACCESSORIES SM-01 Digital I/O Adapter, Convert DB15 to DB9 + 8-pin micro-DIN GTL-248 GPIB Cable, SM-02 Digital I/O Adapter, Convert DB15 to DB37 + 8-pin micro-DIN 2000mm GTL-246 USB Cable (USB 2.0 A-B Type, approx.. 1200mm)

Specifications subject to change without notice.



Ihr Ansprechpartner / Your Partner:

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>>> www.datatec.eu



Simply Reliable

GSM-20H10\_E\_D1BH



Mess- und Prüftechnik. Die Experten.

# CD User manual x 1, Quick Start manual x 1, Test Lead GTL-207A x 1, Alligator Clip x 2

ACCESSORIES



SM-01/SM-02 Digital I/O Adapter